Unit in mm

TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

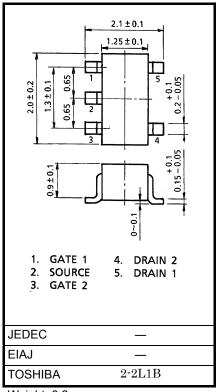
HN4K03JU

High Speed Switching Applications Analog Switch Applications

- High input impedance
- Low gate threshold voltage: $V_{th} = 0.5 \sim 1.5 V$
- Excellent switching times
- Small package

Absolute Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

Characteristic	Symbol	Rating	Unit
Drain-Source voltage	V_{DS}	20	V
Gate-Source voltage	V_{GSS}	10	٧
DC Drain current	ΙD	100	mA
Drain power dissipation	P _D *	200	mW
Channel temperature	T _{ch}	150	°C
Storage temperature range	T _{stg}	-55~150	°C



Weight: 6.2mg

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

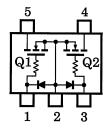
*: Total rating

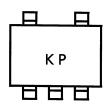
Electrical Characteristics (Ta = 25°C) (Q1, Q2 Common)

Characteristic		Symbol	Test Condition	Min.	Тур.	Max.	Unit
Gate leakage current		I _{GSS}	V _{GS} = 10V, V _{DS} = 0	_	_	1	μΑ
Drain-Source breakdown voltage		V (BR) DSS	I _D = 100μA, V _{GS} = 0	20	_	_	V
Drain cut-off currer	nt	I _{DSS}	V _{DS} = 20V, V _{GS} = 0	_	_	1	μΑ
Gate threshold vol	tage	V _{th}	V _{DS} = 3V, I _D = 0.1mA	0.5	_	1.5	V
Forward transfer admittance		Y _{fs}	V _{DS} = 3V, I _D = 10mA	25	50	_	mS
Drain-Source ON resistance		R _{DS (ON)}	I _D = 10mA, V _{GS} = 2.5V	_	8	12	Ω
Input capacitance		C _{iss}	V _{DS} = 3V, V _{GS} = 0, f = 1MH _z	_	8.5	_	pF
Reverse transfer capacitance		C _{rss}	V _{DS} = 3V, V _{GS} = 0, f = 1MH _z	_	3.3	_	pF
Output capacitance		C _{oss}	V _{DS} = 3V, V _{GS} = 0, f = 1MH _z	_	9.3	_	pF
Switching time	Turn-on time	t _{on}	$V_{DD} = 3V$, $I_D = 10$ mA $V_{GS} = 0 \sim 2.5V$	_	0.16	_	
	Turn-off time	t _{off}	$V_{DD} = 3V$, $I_{D} = 10mA$ $V_{GS} = 0~2.5V$	_	0.15	1	μs

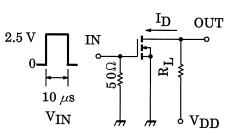
Equivalent Circuit (Top View)

Marking

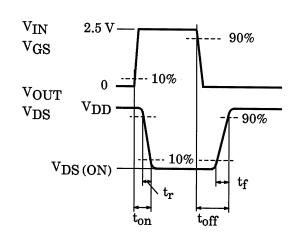


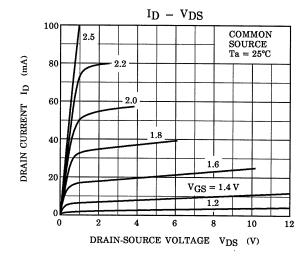


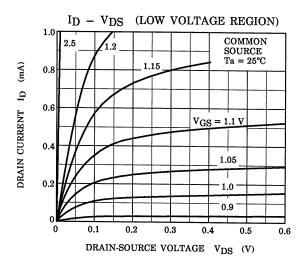
(Q1, Q2 Common) Switching Time Test Circuit

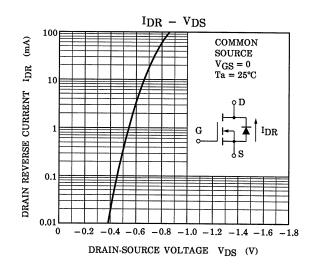


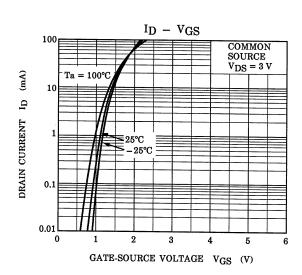
 $V_{DD} = 3 V$ $D.U. \le 1\%$ $V_{IN}: t_r, t_f < 5 \text{ ns}$ $(Z_{out} = 50 \Omega)$ COMMON SOURCE $Ta = 25^{\circ}C$



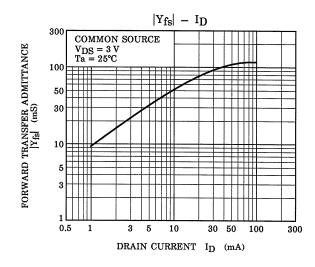


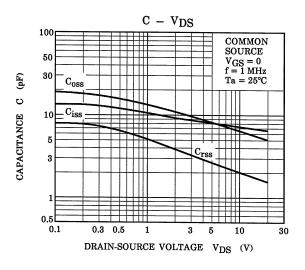


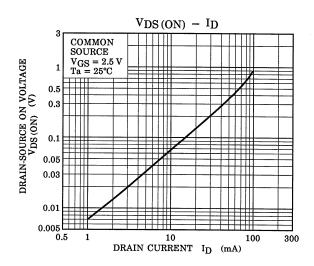


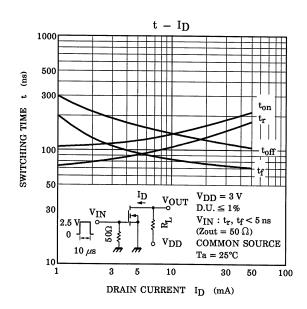


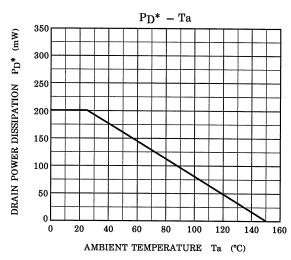
(Q1, Q2 Common)











*: Total Rating

2007-11-01

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20070701-EN GENERAL

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